

100 V

100V N-Channel Enhancement Mode MOSFET

Voltage

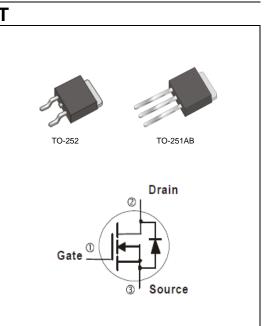
50 A Current

Features

- R_{DS(ON)}, V_{GS}@10V,I_D@30A<22mΩ
- High switching speed ٠
- Improved dv/dt capability
- Low reverse transfer capacitance •
- Lead free in compliance with EU RoHS 2011/65/EU directive. •
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case : TO-251AB, TO-252 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AB Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252 Approx. Weight : 0.0104 ounces, 0.297 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	100	V
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V
Continuous Drain Current	T _C =25°C	l _D	50	
	T _c =100°C		32	А
Pulsed Drain Current	T _C =25°C	I _{DM}	100	
Power Dissipation	T _C =25°C	PD	96	14/
	T _c =100°C		38	W
Continuous Drain Current	T _A =25°C	Ι _D	8	А
	T _A =70°C		6.5	А
Power Dissipation	T _A =25°C		2.5	14/
Power Dissipation	T _A =70°C	PD	1.6	W
Single Pulse Avalanche Energy (Note 1)		E _{AS}	80	mJ
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal Resistance	Junction to Case	$R_{ extsf{ heta}JC}$	1.3	°0 444
	Junction to Ambient	R _{θJA}	50 ^(Note 1)	°C/W





Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	100	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	2.5	3.57	4.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =30A	-	18.3	22	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =80V,V _{GS} =0V	-	0.01	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic (Note 5)						
Total Gate Charge	Qg		-	29	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =50V, I _D =30A, V_{GS} =10V ^(Note 2,3)	-	9.5	-	
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	10	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	1643	-	pF
Output Capacitance	Coss		-	257	-	
Reverse Transfer Capacitance	Crss		-	63	-	
Turn-On Delay Time	td _(on)		-	19	-	ns
Turn-On Rise Time	tr	V _{DD} =50V, I _D =30A, V _{GS} =10V, R _G =3Ω (Note 2.3)	-	56	-	
Turn-Off Delay Time	td _(off)		-	25	-	
Turn-Off Fall Time	t _f		-	13	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I _S		-	-	50	А
Diode Forward Current						
Diode Forward Voltage	V _{SD}	I _S =1A,V _{GS} =0V	-	0.67	1.0	V
Reverse Recovery Time	trr	V _{GS} =0V, I _S =20A	-	31	-	ns
Reverse Recovery Charge	Qrr	dI _F / dt=100A/us ^(Note 2)	-	38	-	uC

NOTES :

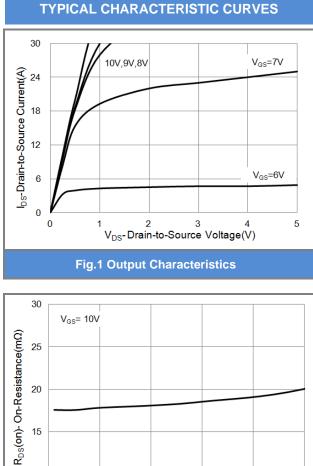
1. The test by surface mounted on 1 inch FR4 board with 2oz copper.

2. L=0.1mH, I_{AS}=40A, V_{DD}=25V, V_{GS}=10V, R_G=25ohm, Starting T_J=25°C

3. The Power dissipation is limit by 150°C junction temperature.

- 4. Pulse width300us, Duty cycle2%
- 5. Guaranteed by design, not subject to production testing





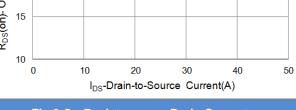
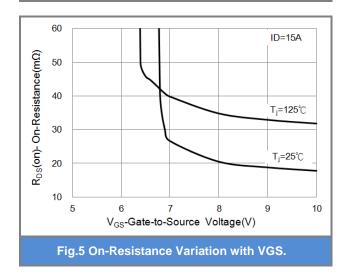


Fig.3 On-Resistance vs. Drain Current



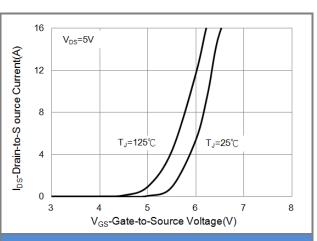


Fig.2 Transfer Characteristics

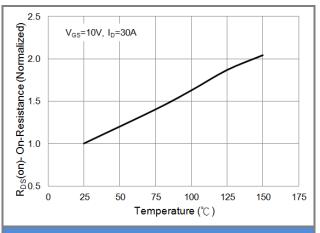
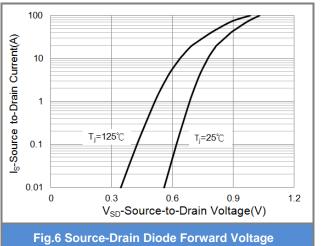


Fig.4 On-Resistsnce vs. Junction temperature





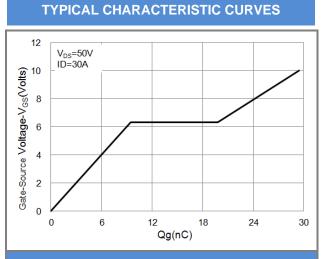
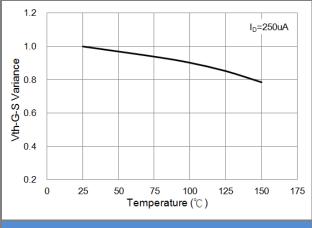
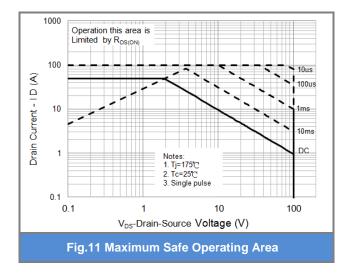
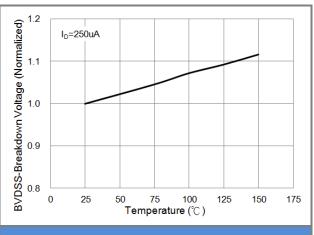


Fig.7 Gate-Charge Characteristics











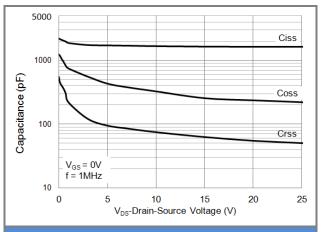
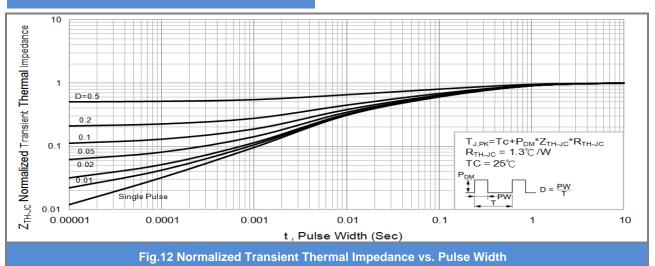


Fig.10 Capacitance vs. Drain-Source Voltage

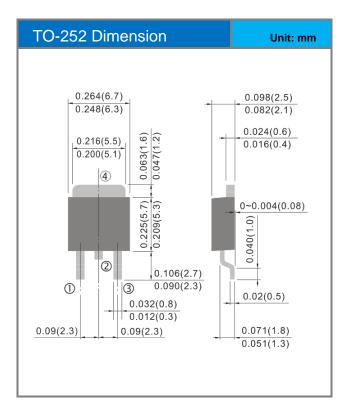


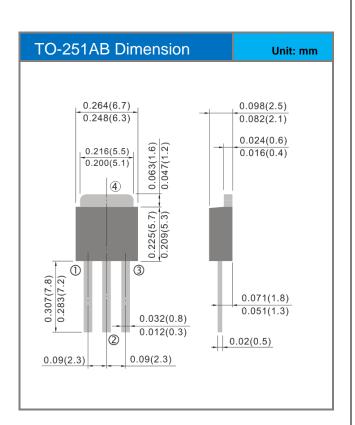






Packaging Information



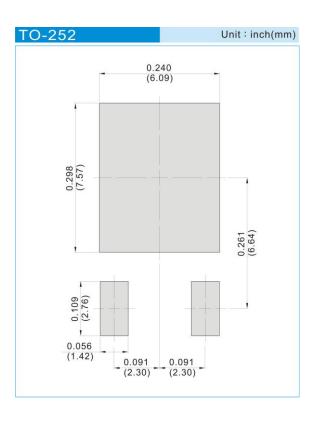




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJD50N10L_L2_00001	TO-252	3,000pcs / 13" reel	D50N10L	Halogen free	
PJU50N10L_T0_00001	TO-251AB	80pcs / Tube	U50N10L	Halogen free	

MOUNTING PAD LAYOUT





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